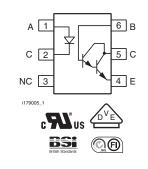
# 4N32, 4N33



**Vishay Semiconductors** 

# Optocoupler, Photodarlington Output, High Gain, With Base Connection





## DESCRIPTION

The 4N32 and 4N33 are optically coupled isolators with a gallium arsenide infrared LED and a solicon photodarlington sensor.

Switching can be achieved while maintaining a high degree of isolation between driving and load circuits.

These optocouplers can be used to replace reed and mercury relays with advantages of long life, high speed switching and elimination of magnetic fields.

## FEATURES

- Very high current transfer ratio, 500 % min.
- High isolation resistance,  $10^{11} \Omega$  typical
- Standard plastic DIP package
- Material categorization:



RoHS

COMPLIANT

for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## AGENCY APPROVALS

- UL1577, file no. E52744 system code H
- DIN EN 60747-5-2 (VDE 0884) / DIN EN 60747-5-5 (pending), available with option 1
- BSI IEC 60950; IEC 60065
- FIMKO

ORDERING INFORMATION		
4 N 3 # -	X 0 # # T PACKAGE OPTION TAPE REL	
AGENCY CERTIFIED/PACKAGE	CTR	(%)
UL, BSI, FIMKO	≥ 500	≥ 500
DIP-6	4N32	4N33

Note

Additional options may be possible, please contact sales office



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<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
input		•				
Reverse voltage		V <sub>R</sub>	3	V		
Forward current		I <sub>F</sub>	60	mA		
Power dissipation		P <sub>diss</sub>	100	mW		
Derate linearly	From 55 °C		1.33	mW/°C		
output			•			
Collector emitter breakdown voltage		BV <sub>CEO</sub>	30	V		
Emitter base breakdown voltage		BV <sub>EBO</sub>	8	V		
Collector base breakdown voltage		BV <sub>CBO</sub>	50	V		
Emitter collector breakdown voltage		BV <sub>ECO</sub>	5	V		
Collector (load) current		Ι <sub>C</sub>	100	mA		
Power dissipation		P <sub>diss</sub>	150	mW		
Derate linearly			2	mW/°C		
coupler		•				
Total dissipation		P <sub>tot</sub>	250	mW		
Derate linearly			3.3	mW/°C		
Isolation test voltage (between emitter	1 s	V <sub>ISO</sub>	5300	V <sub>RMS</sub>		
Leakage path			7	mm min.		
Air path			7	mm min.		
la clatica versistana s	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 25 ^{\circ}\text{C}$	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω		
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}$	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω		
Storage temperature		T <sub>stg</sub>	-55 to +150	°C		
Operating temperature		T <sub>amb</sub>	-55 to +100	°C		
Lead soldering time <sup>(1)</sup>	At 260 °C		10	S		

Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability

<sup>(1)</sup> Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP)

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_{amb} = 25 \text{ °C}$ , unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
input	input							
Forward voltage	I <sub>F</sub> = 50 mA	V <sub>F</sub>	-	1.25	1.5	V		
Reverse current	V <sub>R</sub> = 3 V	I <sub>R</sub>	-	0.1	100	μA		
Capacitance	V <sub>R</sub> = 0 V	C <sub>O</sub>	-	25		pF		
output								
Collector emitter breakdown voltage (1)	$I_{C} = 100 \ \mu A, \ I_{F} = 0$	BV <sub>CEO</sub>	30	-	-	V		
Collector base breakdown voltage (1)	$I_{C} = 100 \ \mu A, \ I_{F} = 0$	BV <sub>CBO</sub>	50	-	-	V		
Emitter base breakdown voltage (1)	$I_{C} = 100 \ \mu A, \ I_{F} = 0$	BV <sub>EBO</sub>	8	-	-	V		
Emitter collector breakdown voltage <sup>(1)</sup>	$I_{C} = 100 \ \mu A, \ I_{F} = 0$	BV <sub>ECO</sub>	5	10	-	V		
Collector emitter leakage current	$V_{CE} = 10 \text{ V}, I_F = 0$	I <sub>CEO</sub>	-	1	100	nA		
	$I_{C} = 0.5 \text{ mA}, V_{CE} = 5 \text{ V}$	h <sub>FE</sub>	13	-	-			
coupler								
Collector emitter saturation voltage		V <sub>CEsat</sub>	-	1	-	V		
Coupling capacitance			-	1.5	-	pF		

#### Notes

 Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements

<sup>(1)</sup> Indicates JEDEC<sup>®</sup> registered values

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CURRENT TRANSFER RATIO						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Current transfer ratio	$V_{CE} = 10 \text{ V}, I_F = 10 \text{ mA}$	CTR	500	-	-	%

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn-on time	$V_{CC} = 10 \text{ V}, \text{ I}_{C} = 50 \text{ mA}$	t <sub>on</sub>	-	-	5	μs
Turn-off time	$I_F$ = 200 mA, $R_L$ = 180 $\Omega$	t <sub>off</sub>	-	-	100	μs

SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Climatic classification	According to IEC 68 part 1		-	55 / 100 / 21	-		
Comparative tracking index		CTI	175	-	399		
V <sub>IOTM</sub>			8000	-	-	V	
V <sub>IORM</sub>			890	-	-	V	
P <sub>SO</sub>			-	-	700	mW	
I <sub>SI</sub>			-	-	400	mA	
T <sub>SI</sub>			-	-	175	°C	
Creepage distance	Standard DIP-6		7	-	-	mm	
Clearance distance	Standard DIP-6		7	-	-	mm	
Insulation thickness, reinforced rated	Per IEC 60950 2.10.5.1		0.4	-	-	mm	

#### Note

• As per IEC 60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits

### **TYPICAL CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

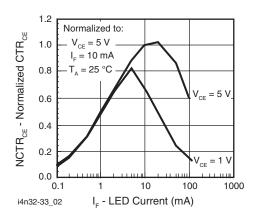


Fig. 1 - Normalized Non-Saturated and Saturated  $\mbox{CTR}_{\mbox{CE}}$  vs. LED Current

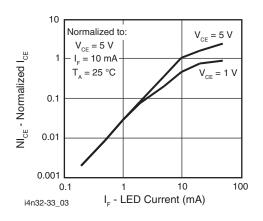
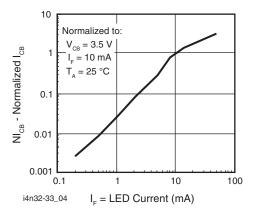


Fig. 2 - Normalized Non-Saturated and Saturated Collector Emitter Current vs. LED Current

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Fig. 3 - Normalized Collector Base Photocurrent vs. LED Current

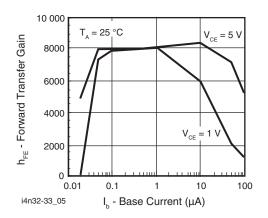
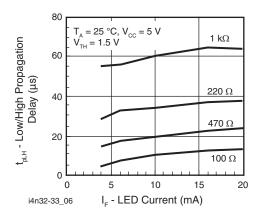


Fig. 4 - Non-Saturated and Saturated h<sub>FE</sub> vs. Base Current





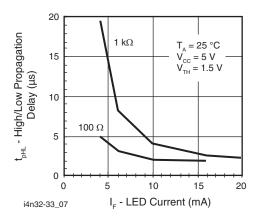


Fig. 6 - High to Low Propagation Delay vs. Collector Load Resistance and LED Current

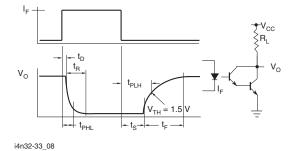


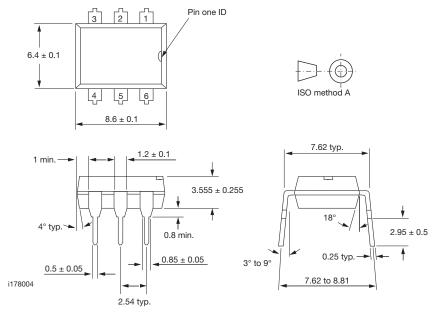
Fig. 7 - Switching Waveform and Switching Schematic



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### **PACKAGE DIMENSIONS** in millimeters

#### DIP-6 Package Dimensions



### **PACKAGE MARKING**



#### Notes

- Example marking for 4N32
- Only options 1, and 7 reflected in the package marking
- The VDE logo is only marked on option 1 parts
- Tape and reel suffix (T) is not part of the package marking



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